



EYP-DFB-0780-00080-1500-TOV01-0005 Revision 0.81

SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser



General Product Information	duct Information
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ectroscopy (Rb D2 line)
etrology
z Generation



Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	T _S	°C	-40		85
Operational Temperature at Case	T_{C}	°C	-20		75
Operational Temperature at Laser Chip	T_{LD}	°C	0		50
Forward Current	I _F	mA			200
Reverse Voltage	V_R	V			2
Output Power	P _{opt}	mW			100
TEC Current	I _{TEC}	А			1.0
TEC Voltage	V_{TEC}	V			1.0

Measurement Conditions / Comments

Stress in excess of one of the Absolute Maximum Ratings may damage the laser. Please note that a damaging optical power level may occur although the maximum current is not reached. These are stress ratings only, and functional operation at these or any other conditions beyond those indicated under Recommended Operational Conditions is not implied.

Recommended Operational Conditions

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	T_{case}	°C	-20		65
Operational Temperature at Laser Chip	T_LD	°C	5		45
Forward Current	I _F	mA			180
Output Power	P _{opt}	mW	20		80

Measurement Conditions / Comments
measured by integrated Thermistor

Characteristics at T_{LD} = 25° C at BOL

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	λ_{C}	nm	779	780	781
Target Wavelength	λ_{T}	nm		780.24	
Linewidth (FWHM)	Δλ	MHz		0.6	1
Sidemode Supression Ratio	SMSR	dB	30	45	
Temperature Coefficient of Wavelength	$d\lambda/dT$	nm / K		0.06	
Current Coefficient of Wavelength	dλ / dI	nm / mA		0.003	

Measurement Conditions / Comments
see images on page 4
reached within $T_{LD} = 5$ ° 45 ° C at 80 mW
$P_{opt} = 80 \text{ mW}$
$P_{opt} = 80 \text{ mW}$

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Characteristics at T _{LD} = 25° (Cat BOL				cont'd
Parameter	Symbol	Unit	min	typ	max
Mode-hop free Tuning Range	$\Delta \lambda_{\text{tune}}$	pm	25		
Laser Current @ $P_{opt} = 80 \text{ mW}$	I_{LD}	mA			180
Slope Efficiency	η	W/A	0.6	0.8	1.1
Threshold Current	I _{th}	mA			70
Divergence parallel (FWHM)	$\Theta_{ }$	0		8	
Divergence perpendicular (FWHM)	Θ_{\perp}	0		21	
Degree of Polarization	DOP	%		90	

Measurement Conditions / Comments
> 10 GHz, at target wavelength
parallel to Pin 1 - Pin 6 plane (see p. 3)
perpendicular to Pin 1 - Pin 6 plane (see p. 3)
$P_{opt} = 80$ mW; E field perpendicular to $$ Pin 1 - 6 plane

Parameter	Symbol	Unit	min	typ	max
Monitor Detector Responsivity	I _{mon} / P _{opt}	μA/mW		t.b.d.	

Meas	urement Conditions / Comments
$U_R =$	5 V

Thermoelectric Cooler					
Parameter	Symbol	Unit	min	typ	max
Current	I _{TEC}	А		0.4	
Voltage	U_TEC	V		0.4	
Power Dissipation (total loss at case)	P _{loss}	W		0.4	
Temperature Difference	ΔΤ	K			40

Measurement Conditions / Comments						
P _{opt} =	80 mW	, ΔT =	20 K			
P _{opt} =	80 mW	, ΔT =	20 K			
P _{opt} =	80 mW	, ΔT =	20 K			
P _{opt} =	80 mW	, ΔT =	Tcase	- TLD		

l Unit	min	typ 10	max
kΩ		10	
		3930	
		1.029 x 10	-3
		2.510 x 10	-4
		1.051 x 10	-7
			2.510 x 10

$T_{LD} = 25^{\circ} C$			
$R_1 / R_2 = e^{\beta (1/T_1 - 1/T_2)}$ at $T_{LD} =$	0° 50° C		
$1/T = A + B(\ln R) + C(\ln R)^3$			
T: temperature in Kelvin			
R: resistance at T in Ohm			

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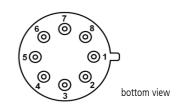
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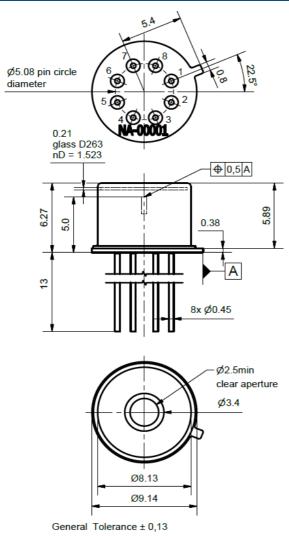
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Pin Assignment								
1	Laser Diode Anode	5	Thermistor					
2	Laser Diode Cathode	6	Thermistor					
3	Thermoelectric Cooler (-)	7	Photo Diode Anode					
4	Thermoelectric Cooler (+)	8	Photo Diode Cathode					
All 8 pins are isolated from case.								



Package Drawings



AIZ-19-0129-1426B

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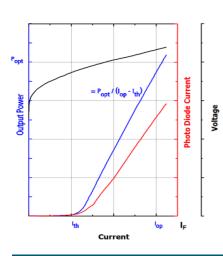
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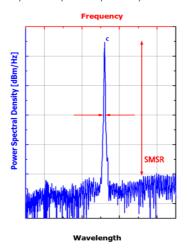


Typical Measurement Results

Output Power vs. Current



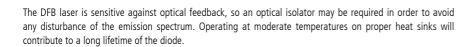
Spectra at Specified Optical Output Power



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.



Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.

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